

### **WAS7227Q**

### USB High speed (480Mbps), DPDT Analog Switch

### **Descriptions**

The WAS7227Q is a high performance, double pole double throw (DPDT) CMOS analog switch that operates from a single +2.5V to +4.5V power supply.

The WAS7227Q is designed for switching of high-speed USB2.0 signals in handset and consumer applications, such as cell phones, digital cameras, and notebooks with hubs or controllers with limited USB I/Os.

The WAS7227Q has low bit-to-bit skew and high channel-to-channel noise isolation, and is compatible with various standards, such as high-speed USB 2.0 (480Mbps). Each switch is bi-directional and offers little attenuation of the high-speed signals at the outputs. Its bandwidth is quite marginal to pass high-speed USB 2.0 differential signals (480Mbps) with good signal integrity.

The WAS7227Q is featured with special circuitry on the D+/D-, which allows the device to withstand a VBUS short to D+ or D- when the USB devices are either powered off or on.

The SEL/OE pin has overvoltage protection that allows voltages above VCC, up to 7.0V to be present on the pin without damage or disruption of operation of the part, regardless of the operating voltage. The WAS7227Q is also featured with smart circuitry to minimize VCC leakage current even when SEL/OE control voltage is lower than VCC supply voltage. In other word, there is no need of additional device to shift SEL/OE level to be the same as that of VCC in real application.

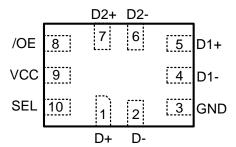
The WAS7227Q is available in QFN1418-10L package. Standard products are Pb-Free and halogen-Free.

### **Applications**

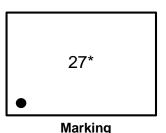
- Cell phones
- MID
- Router
- Other electronics equipments

### Http//:www.sh-willsemi.com





Pin configuration (Top view)



warking

27 = Device code

' = Month (A~Z)

### **Order information**

Device	Package	Shipping	
WAS7227Q-10/TR	QFN1418-10L	3000/Reel&Tape	

### **Features**

Supply voltage : 2.5~ 4.5V

-3dB Bandwidth : 550MHz @ C<sub>L</sub>=5pF
 Off isolation : -38dB @ 250MHz
 Crosstalk : -47dB @ 250MHz

Low quiescent current : <1uA</li>



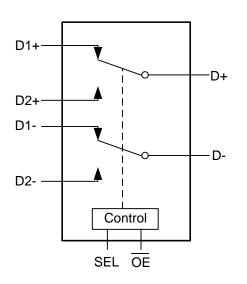
Pin descriptions

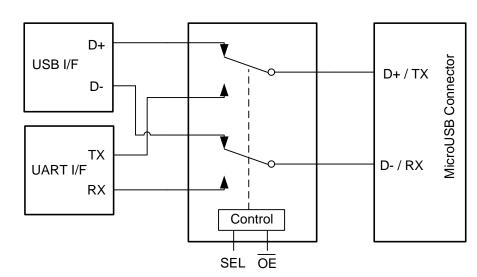
Pin Number	Symbol	Descriptions
1	D+	Port A common data terminal, Connect to D1+ or D2+ according to SEL logic
2	D-	Port B common data terminal, Connect to D1- or D2- according to SEL logic
3	GND	Ground
4	D1-	Port B data 1 terminal
5	D1+	Port A data 1 terminal
6	D2-	Port B data 2 terminal
7	D2+	Port A data 2 terminal
8	ŌĒ	Enable control, Active low
9	VCC	Power supply
10	SEL	Switch select pin, digital logic low or high

## **Function descriptions**

SEL	ŌĒ	Function	
X	Н	Switch disconnected	
L	L	D+ connect to D1+ and D- connect to D1-	
Н	L	D+ connect to D2+ and D- connect to D2-	

# Logic symbol and typical applications





Logic Symbol

**Typical Applications** 



**Absolute maximum ratings** 

Parameter	Symbol	Value	Unit
Supply voltage range	VCC	-0.3 ~ 6.5	V
Data input/output voltage range	V <sub>AC</sub>	-0.3 ~ 6.5	V
Select input voltage range	V <sub>SEL</sub>	-0.3 ~ 6.5	V
Continues output current	I <sub>OUT</sub>	±50	mA
Junction temperature range	T <sub>J</sub>	150	°C
Lead temperature range	T <sub>L</sub>	260	°C
Storage temperature range	T <sub>STG</sub>	-65 ~ 150	°C
Thermal resistance	$R_{\theta JA}$	250	°C/W
ESD protection (HBM)	All pins to GND	±8000	V
ESD protection (CDM)	All pins	±2000	V

**Recommend operating ratings** 

Parameter	Symbol	Value	Unit
Supply voltage range	VCC	2.5 ~ 4.5	V
Data input/output voltage range	V <sub>IS</sub>	0.0 ~ VCC	V
Select input voltage range	$V_{SEL}$	0.0 ~ VCC	V
Enable control input voltage range	$V_{OE}$	0.0 ~ VCC	V
Operating temperature range	T <sub>OPR</sub>	-40 ~ 85	°C

- 1. "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied.
- 2. The input and output negative voltage ratings may be exceeded if the input and output diode current ratings are observed.
- 3. Control input must be held high or Low, it must not float.

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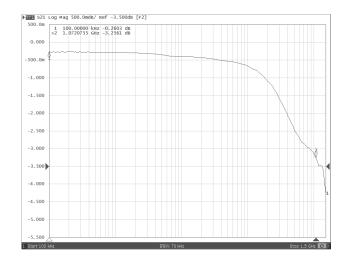


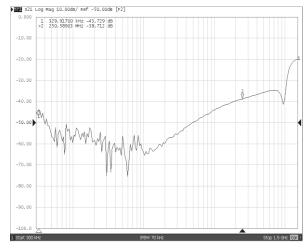
## Electronics Characteristics (Ta=25°C, VCC=4.5V, unless otherwise noted)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Salast and OF logic high lovel	V	VCC=3.0~4.5	1.6			V
Select and OE logic high level	V <sub>IH</sub>	VCC=2.5~3.0	1.4			V
0.1	\/	VCC=3.0~4.5			0.6	V
Select and OE logic low level	V <sub>IL</sub>	VCC=2.5~3.0			0.4	V
Supply quiescent current	I <sub>cc</sub>	I <sub>OUT</sub> =0, V <sub>SEL</sub> >1.5V or V <sub>SEL</sub> <0.7V Refer to figure1			1.0	uA
Select pin leakage current	I <sub>SEL</sub>	V <sub>SEL</sub> =VCC			±1.0	uA
Off state leakage current	I <sub>OFF</sub>	Figure 2			±1.0	uA
On state switch leakage current	I <sub>ON</sub>	Figure 3			±1.0	uA
On-Resistance	R <sub>ON</sub>	VCC=3.0V, $V_{IS}$ =0~0.4V, $I_{OUT}$ =8mA, Figure 4		5.0	7.5	Ω
On-Resistance match	ΔR <sub>ON</sub>	VCC=3.0V, $V_{IS}$ =0~0.4V, $I_{OUT}$ =8mA, Figure 4		0.1	0.2	Ω
On-Resistance flatness	R <sub>FLAT(ON)</sub>	VCC=3.0V, V <sub>IS</sub> =0~1.0V, I <sub>OUT</sub> =8mA, See figure 4		1.8	2.2	Ω
Propagation delay time	T <sub>PLH</sub> / T <sub>PHL</sub>	$C_L$ =5pF, $R_L$ =50 $\Omega$ Figure 5		0.25		ns
Select input to switch on time	T <sub>ON</sub>	$C_L$ =10pF, $R_L$ =50 $\Omega$ Figure 6		48	70	ns
Select input to switch off time	T <sub>OFF</sub>	$C_L$ =10pF, $R_L$ =50 $\Omega$ Figure 6		43	65	ns
Break-Before-Make time	T <sub>BBM</sub>	Generated by design	0.5			ns
2dD Downdridth	BW	$R_L=50\Omega$ , $C_L=5pF$		550		MHz
-3dB Bandwidth		$R_L=50\Omega$ , $C_L=0pF$		800		IVITAL
Off isolation	OIRR	$R_L=50\Omega$ , $F=250MHz$		-38		dB
Crosstalk	Xtalk	$R_L=50\Omega$ , $F=250MHz$		-47		dB
Select pin input capacitance	C <sub>IN</sub>	VCC=0V		3.5		pF
D1n, D2n,Dn Off capacitance	C <sub>OFF</sub>	VCC=3.3V, OE=3.3V		2.5		pF
D1n, D2n,Dn On capacitance	C <sub>ON</sub>	VCC=3.3V, OE=0V		3.8		pF

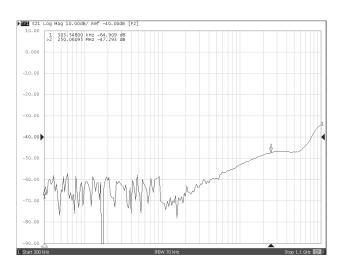


### Typical Characteristics (Ta=25°C, VCC=4.5V, unless otherwise noted)

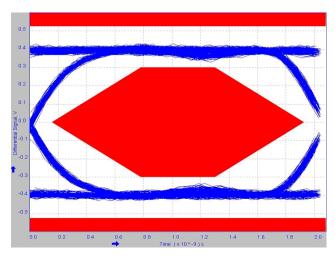




### **Bandwidth**



### Off isolation



Crosstalk

Eye Diagram (480Mbps)

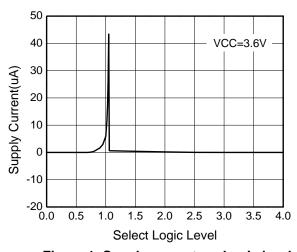
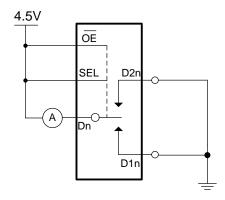


Figure 1: Supply current vs. Logic level



### **Test Circuit**



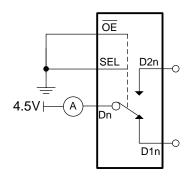
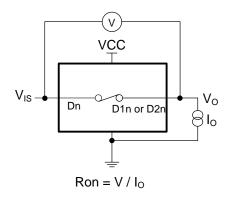


Figure 2: Off state leakage current

Figure 3: On state leakage current



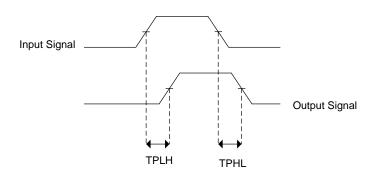


Figure 4: On-Resistance

V<sub>IN</sub>=VCC

Dn

D2n

CL

RL

RL

SEL

Figure 5: Propagation delay time

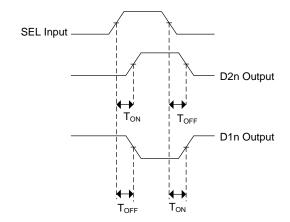
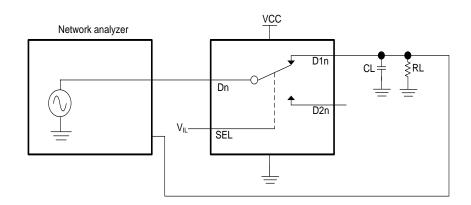
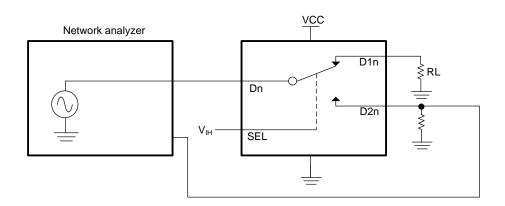


Figure 6: Select input to switch on/off time

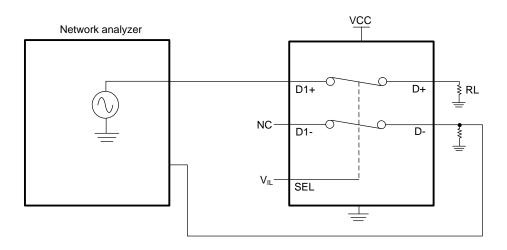




### Bandwidth (BW)



## Off isolation (OIRR)



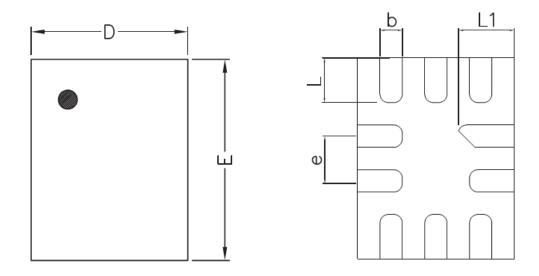
Crosstalk (Xtalk)

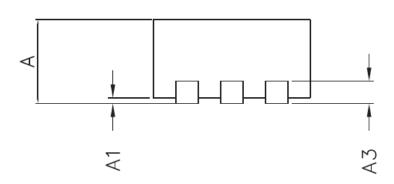
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# Package outline dimensions

# QFN1418-10L





Symbol	Dimension in Millimeters		
	Min.	Max.	
А	0.450	0.550	
A1	0.000	0.050	
A3	0.152 Ref.		
D	1.350	1.450	
E	1.750	1.850	
b	0.150	0.250	
е	0.400 Typ.		
L	0.350	0.450	
L1	0.450	0.550	